TOSHIBA Photocoupler IRED & Photo-Transistor

TLP620, TLP620-2, TLP620-4

Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA TLP620, -2 and -4 consists of a photo–transistor optically coupled to two infrared emitting diode connected in inverse parallel.

The TLP620–2 offers two isolated channels in an eight lead plastic DIP, while the TLP620–4 provides four isolated channels in a sixteen plastic DIP

- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 50% (min.) Rank GB: 100% (min.)
- Isolation voltage: 5000V_{rms} (min.)
- · Safety Standards
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When an VDE approved type is needed, please designate the **Option(D4)**.

7.62 mm pitch 10.16 mm pitch standard type TLP×××F type

• Creepage distance

Clearance

: 6.4 mm (min)

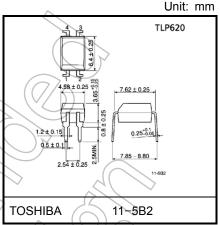
8.0 mm (min) 8.0 mm (min)

Insulation thickness

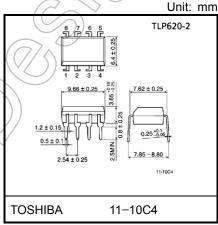
: 0.4 mm (min)

: 6.4 mm (min)

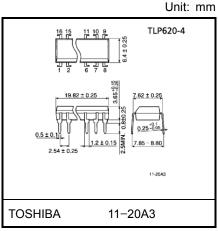
0.4 mm (min)



Weight: 0.26 g (typ.)



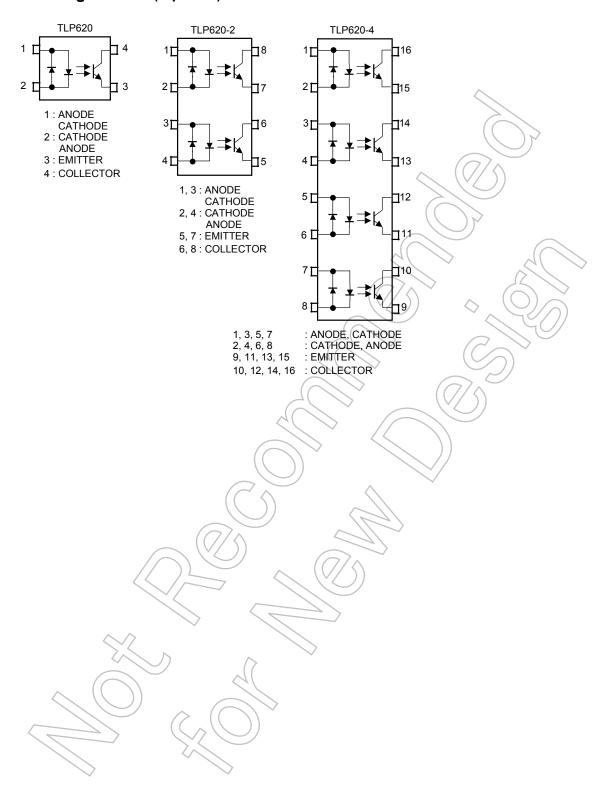
Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1984-01

Pin Configurations (top view)



Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | | Rat | | |
|---|--|----------------------|--------------------------|----------------------|------------------|
| | | Symbol | TLP620 | TLP620-2 TLP620-4 | Unit |
| | Forward current | IF (RMS) | 60 | 50 | mA |
| | Forward current derating | ΔIF / °C | –0.7 (Ta ≥ 39°C) | –0.5 (Ta ≥ 25°C) | mA / °C |
| _ | Pulse forward current | lfp | ±1 (100μs pulse, 100pps) | | Α |
| LED | Power dissipation (1 circuit) | PD | 100 | 70 | mW |
| | Power dissipation derating (1 circuit) | ΔP _D / °C | -1.2 (Ta ≥ 39°C) | -0.7 (Ta ≥ 25°C) | mW / °C |
| | Junction temperature | Tj | 12 | 25 | °C |
| | Collector-emitter voltage | VCEO | (5 | 5 | V |
| | Emitter-collector voltage | VECO | 7 | | V |
| ٦٢ | Collector current | IC | 50 | | mA |
| Detector | Collector power dissipation (1 circuit) | PC | 150 | 100 | mW |
| | Collector power dissipation derating (1 circuit) (Ta ≥ 25°C) | ΔP _C / °C | -1.5 | → -1.0 | mW / °C |
| | Junction temperature | Tj | 12 | 25 | °C |
| Storage temperature range | | T _{stg} | -55~ | -125 | °C |
| Operating temperature range | | T _{opr} | -55~ | 100 | °C |
| Lead soldering temperature | | T _{sold} | 260 (| 10 s) | °C |
| Total package power dissipation (1 circuit) | | PT C | 250 | 150 | mW |
| Total package power dissipation derating (Ta ≥ 25°C, 1 circuit) | | ΔPT/°C | -2.5 | -1.5 | mW / °C |
| Isolation voltage (Note1) | | BVS | 5000 (AC, 60 s | s., RH ≤ 60 %) | V _{rms} |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

| Characteristic | Symbol | Min | Тур. | Max | Unit |
|-----------------------|----------|-----|------|-----|------|
| Supply voltage | Vcc | _ | 5 | 24 | V |
| Forward current | IF (RMS) | _ | 16 | 25 | mA |
| Collector current | Ic | _ | 1 | 10 | mA |
| Operating temperature | Topr | -25 | _ | 85 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

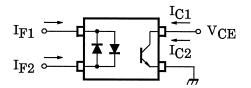
Individual Electrical Characteristics (Ta = 25°C)

| | Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------|-------------------------------------|------------|------------------------------------|-----|------|-----|------|
| | Forward voltage | VF | I _F = ±10 mA | 1,0 | 1.15 | 1.3 | V |
| LED | Forward current | lF | V _F = ±0.7 V | 7 | 2.5 | 20 | μΑ |
| | Capacitance | Ст | V = 0 V, f = 1 MHz | | 60 | | pF |
| | Collector–emitter breakdown voltage | V (BR) CEO | I _C = 0.5 mA | 55 | _ | 1 | ٧ |
| Detector | Emitter–collector breakdown voltage | V (BR) ECO | IE = 0:1 mA | 7 | ı | 1 | ٧ |
| | Collector dark current | ICEO | V _{CE} = 24 V | _ | 10 | 100 | nA |
| | Collector dark current | | V _{CE} = 24 V, Ta = 85 °C | _ | 2 | 50 | μA |
| | Capacitance (collector to emitter) | CCE | V _{CE} = 0 V, f = 1 MHz | _ | 10 | _ | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|----------------------|---|------|------|-----|------|
| Current transfer ratio | IC/IF | IF = ±5 mA, V _{CE} = 5 V Rank GB | 50 | ı | 600 | % |
| Current transfer fatto | | | 100 | 1 | 600 | |
| Saturated CTR | IC / IF (sat) | IF = ±1 mA, V _{CE} = 0.4 V Rank GB | | 60 | _ | % |
| Saturated CTK | | | 30 | | _ | |
| Collector-emitter saturation voltage | VCE (sat) | IC = 2.4 mA, IF = ±8 mA | _ | _ | 0.4 | |
| | | VCE (sat) IC = 0.2 mA, IF = ±1 mA Rank GB | _ | 0.2 | _ | V |
| | | | _ | _ | 0.4 | |
| Off-state collector current | I _{C (off)} | $V_F = \pm 0.7 \text{ V}, V_{CE} = 24 \text{ V}$ | | 1 | 10 | μΑ |
| CTR symmetry (Note.) | IC (ratio) | $I_{C} (I_{F} = -5 \text{ mA}) / I_{C} (I_{F} = +5 \text{ mA})$ | 0.33 | _ | 3 | _ |

Note : $I_{C(ratio)} = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$



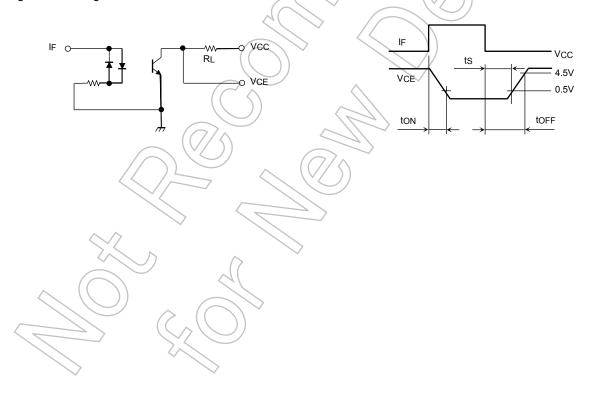
Isolation Characteristics (Ta = 25°C)

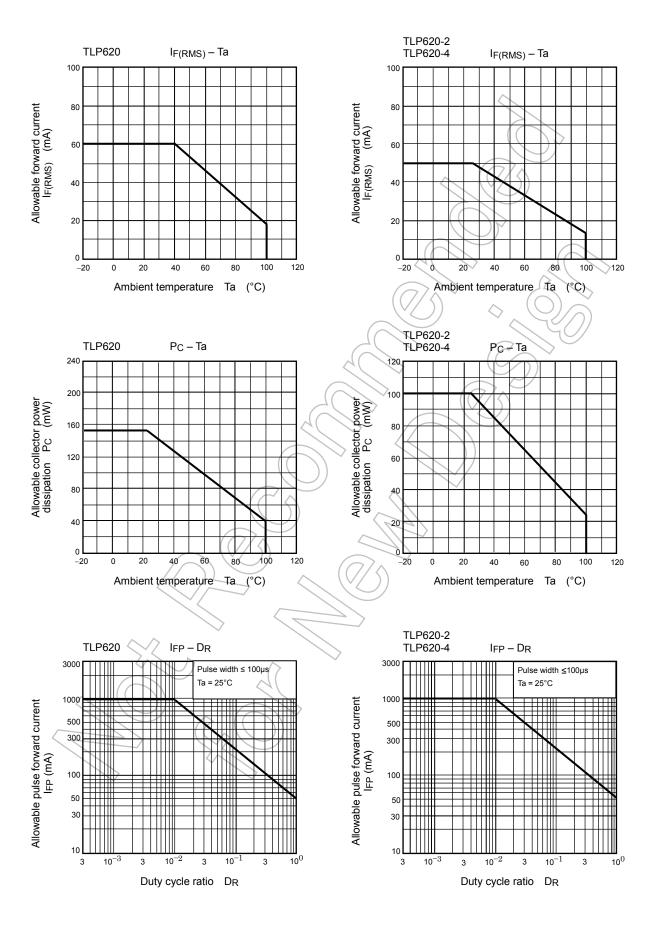
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------------|--------|-------------------------------------|--------------------|------------------|-----|------------------|
| Capacitance input to output | Cs | V _S = 0 V, f = 1 MHz | - | 0.8 | _ | pF |
| Isolation resistance | Rs | V _S = 500 V, R.H. ≤ 60 % | 1×10 ¹² | 10 ¹⁴ | _ | Ω |
| Isolation voltage | BVS | AC, 60 s | 5000 | _ | _ | V _{rms} |

Switching Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------|--------|--|----------------|------|--------|------|
| Rise time | tr | (()> | _ | 2 | - | μs |
| Fall time | tf | Vcc = 10 V | _ | 3 | 1 | |
| Turn-on time | ton | I _C = 2 mA R _L = 100 Ω | _ | (3 | ϕ | |
| Turn-off time | toff | | -0 | 3 | | |
| Turn-on time | ton | | +(|))2 | _ | |
| Storage time | ts | $R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = \pm 16 \text{ mA}$ | (- | (15) | _ | μs |
| Turn-off time | toff | | 7 _ | 25 | _ | |

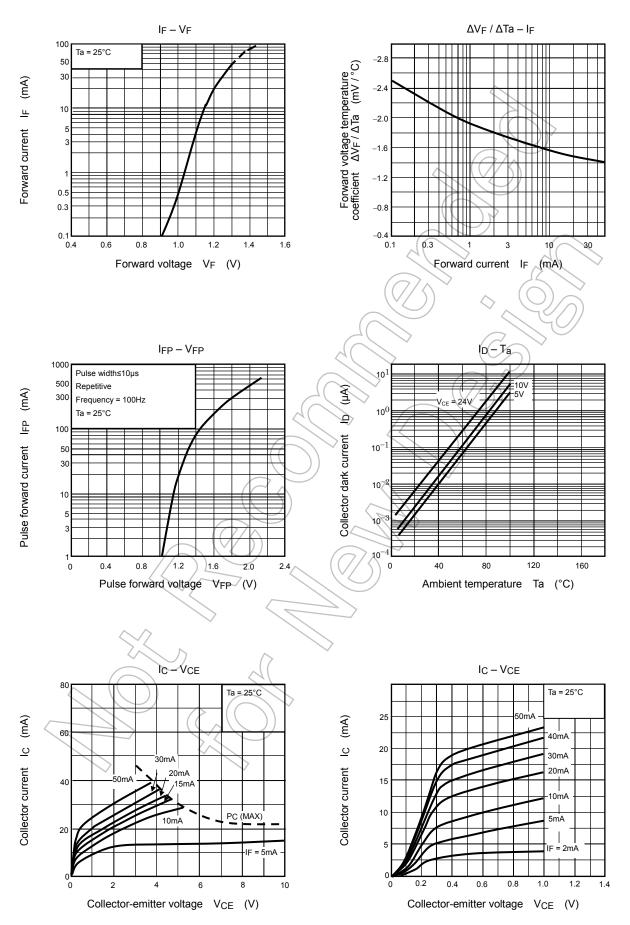
Fig. 1 Switching time test circuit



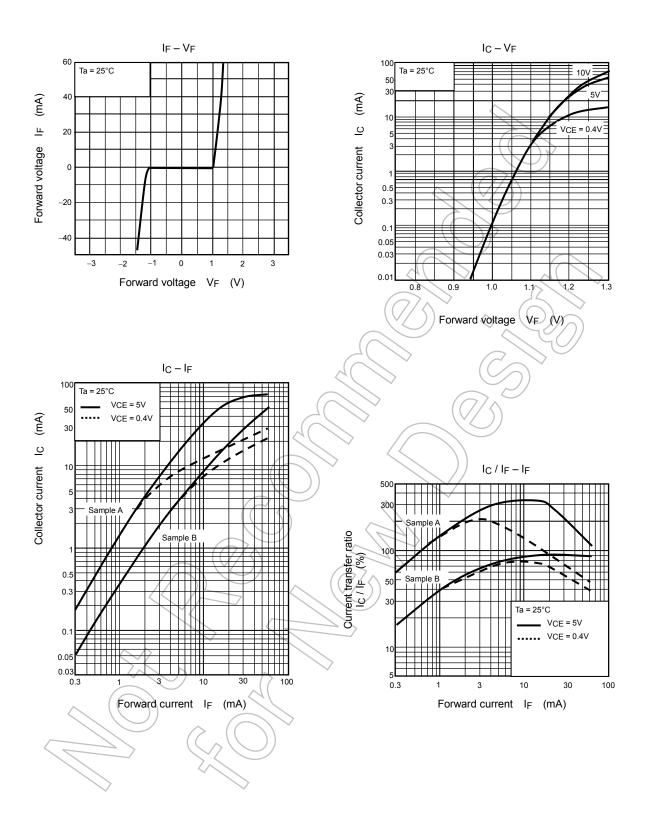


NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

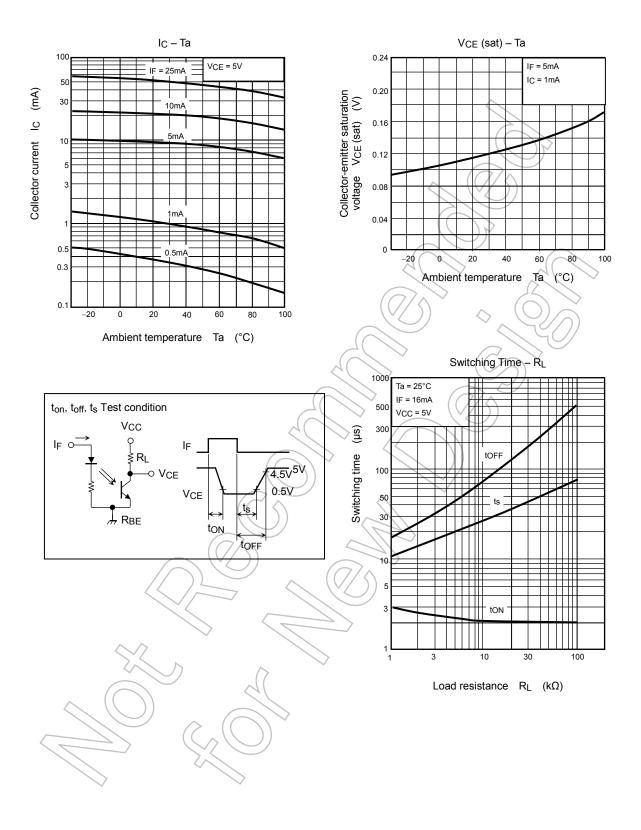
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